# High-speed Switching Transistor (–60V, –5A) **2SA1952**

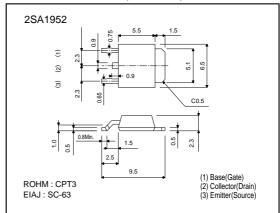
### Features

- 1) High speed switching. (tf : Typ. 0.15  $\mu$ s at Ic = -3A)
- 2) Low VcE(sat). (Typ. -0.2V at Ic/IB = -3/-0.15A)
- 3) Wide SOA. (safe operating area)
- 4) Complements the 2SC5103.

# ● Absolute maximum ratings (Ta = 25°C)

| Parameter                   | Symbol | Limits   | Unit       |
|-----------------------------|--------|----------|------------|
| Collector-base voltage      | Vсво   | -100     | V          |
| Collector-emitter voltage   | Vceo   | -60      | V          |
| Emitter-base voltage        | Vebo   | -5       | V          |
| Collector current           | Ic     | -5       | Α          |
| Collector current           | IC IC  | -10      | A(Pulse)   |
| Collector power dissipation | Pc     | 1        | W          |
| Collector power dissipation | FC     | 10       | W(Tc=25°C) |
| Junction temperature        | Tj     | 150      | °C         |
| Storage temperature         | Tstg   | -55~+150 | °C         |

# ●External dimensions (Units : mm)



### Packaging specifications and hre

| Туре                         | 2SA1952 |  |  |
|------------------------------|---------|--|--|
| Package                      | CPT3    |  |  |
| hfE                          | Q       |  |  |
| Code                         | TL      |  |  |
| Basic ordering unit (pieces) | 2500    |  |  |

# ● Electrical characteristics (Ta = 25°C)

|                                      | •                    |      |      |      |      |                                  |
|--------------------------------------|----------------------|------|------|------|------|----------------------------------|
| Parameter                            | Symbol               | Min. | Тур. | Max. | Unit | Conditions                       |
| Collector-base breakdown voltage     | ВУсво                | -100 | -    | -    | V    | Ic=-50μA                         |
| Collector-emitter breakdown voltage  | BVceo                | -60  | -    | -    | V    | Ic=-1mA                          |
| Emitter-base breakdown voltage       | ВVево                | -5   | -    | -    | V    | Iε = -50μA                       |
| Collector cutoff current             | Ісво                 | -    | -    | -10  | μА   | VcB = -100V                      |
| Emitter cutoff current               | ІЕВО                 | -    | -    | -10  | μΑ   | VEB = -5V                        |
| Collector-emitter saturation voltage | VCE(sat)             | -    | -    | -0.3 | V    | Ic/I <sub>B</sub> =-3A/-0.15A    |
|                                      |                      | -    | -    | -0.5 | V    | Ic/I <sub>B</sub> =-4A/-0.2A     |
| Base-emitter saturation voltage      | V <sub>BE(sat)</sub> | -    | -    | -1.2 | V    | Ic/I <sub>B</sub> =-3A/-0.15A    |
|                                      |                      | -    | -    | -1.5 | V    | Ic/I <sub>B</sub> =-4A/-0.2A     |
| DC current transfer ratio            | hre                  | 120  | -    | 270  | -    | Vc= -2V, Ic=-1A                  |
| Transition frequency                 | f⊤                   | -    | 80   | -    | MHz  | Vce = -10V, IE = 0.5A, f = 30MHz |
| Output capacitance                   | Cob                  | -    | 130  | -    | pF   | Vcb = -10V , IE = 0A , f = 1MHz  |
| Turn-on time                         | ton                  | -    | -    | 0.3  | μs   | $I_C = -3A$ , $R_L = 10\Omega$   |
| Storage time                         | tstg                 | -    | -    | 1.5  | μs   | $I_{B1} = -I_{B2} = -0.15A$      |
| Fall time                            | tf                   | -    | _    | 0.3  | μs   | Vcc≃-30V                         |



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